# F.E. (ETC/ECE) (Semester - II) (RC) (2007 - 2008) Examination, Sept. 2021

## **BASIC ELECTRONICS ENGINEERING**

Duration: 3 Hours Total Marks: 60

#### Instructions:

1. Answer any three questions, selecting only one question from each module

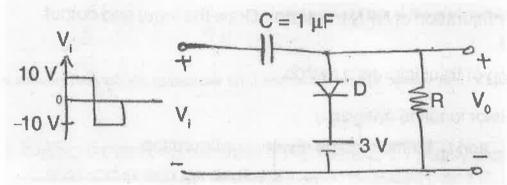
2. Assume suitable data if necessary.

2. Notations have their usual meaning.

3. Figures to the right indicate full marks

#### **MODULE-I**

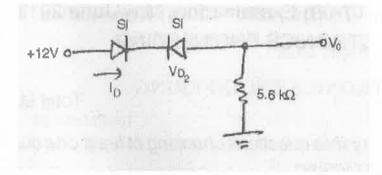
- 1. a) Draw and explain the center tapped full wave rectifier and derive the expression for ratio of rectification [10]
  - b) Distinguish between Avalanche and Zener breakdown mechanisms in a semiconductor diode [6]
  - c) Determine the output waveform for the following circuit assuming RC constant is very large and diode is ideal [4]



2. a) Why is a filter required in a DC power supply? Draw the circuit of a C- filter and explain the output waveform [5]

[5]

- b) Draw and explain the operation of a half wave voltage doubler.
- c) Determine I<sub>D</sub>, V<sub>D</sub> and Vo for the following circuit

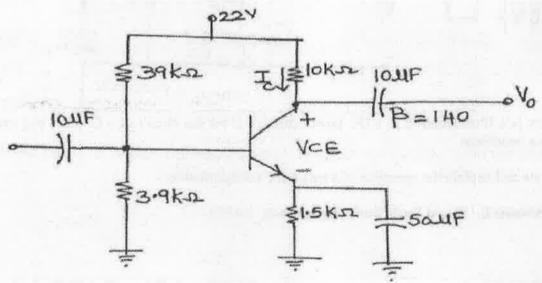


d) What is an ideal diode? Sketch the characteristics of an ideal diode [4]

[6]

### **MODULE-II**

- 3. a) Compare the biasing method of transistor. Which is the best biasing technique. Explain any one biasing technique. [6]
  - b) What do you mean by stabilization of operating point? Explain the reasons why stabilization of Q-point is necessary [6]
  - c) Explain how a transistor can be used as an amplifier. [4]
  - d) Derive the relation between  $I_C$  and  $I_{CEO}$  for a transistor. [4]
- 4. a) Determine the DC bias voltage  $V_{CE}$  and the current  $I_C$  for the voltage divider configuration of the fig. below [8]



b) What is thermal runaway? How can it be controlled?	[4]
c) Explain the design and operation of transistor as a switch.	[4]
d) Explain transistor load line analysis.	[4]
MODULE-III	
5. a) Draw and explain the drain to source characteristics of P-channel JFET. Also explain he transfer curve is obtained from the output characteristics.	ow the [8]
b) With the help of a neat diagram explain how a Complementary MOSFET can be used inverter	as an [6]
c) Explain the biasing circuit of an enhancement mode MOSFET	[6]
6. a) Explain the operation of an n-channel depletion type MOSFET. Sketch the device drain characteristics.	[8]
b) With neat circuit diagrams explain the analysis of FET fixed bias circuit and obtain express for various voltages	sions [6]
c) With the help of a neat diagram explain the self- biasing configuration of a JFET.	[6]
MODULE-IV	
7. a) Explain the grown-junction and diffusion methods to manufacture discrete transistors, with diagrams	h neat [8]
b) Explain the op-amp operation in brief with differential input	[6]
c) Explain the concept of feedbach and draw the block diagram of basic feedback amplifier.	[6]
8. a) Explain the operation of SCR	[8]
b) Explain the working of reflective type field- effect LCD with diagram	[6]

c) Write short notes on any 2:.

[6]

- i) IR Emitters
- ii) Solar Cells
- iii) Thermistor